# VS-26MT.., VS-36MT.. Series

Vishay Semiconductors

COMPLIANT





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| PRIMARY CHARACTERISTICS |                    |  |  |
|-------------------------|--------------------|--|--|
| Ι <sub>Ο</sub>          | 25 A, 35 A         |  |  |
| V <sub>RRM</sub>        | 50 V to 1600 V     |  |  |
| Package                 | D-63               |  |  |
| Circuit configuration   | Three phase bridge |  |  |

#### **FEATURES**

- Universal, 3 way terminals: push-on, wrap around or solder RoHS
- High thermal conductivity package, electrically insulated case
- Center hole fixing
- Excellent power/volume ratio
- UL E300359 approved 🔊
- Nickel plated terminals solderable using lead (Pb)-free solder; solder alloy Sn/Ag/Cu (SAC305); solder temperature 260 °C to 275 °C
- Designed and qualified for industrial and consumer level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

A range of extremely compact, encapsulated three phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and instrumentation applications.

| MAJOR RATINGS AND CHARACTERISTICS |                 |                |                |                  |  |
|-----------------------------------|-----------------|----------------|----------------|------------------|--|
| SYMBOL                            | CHARACTERISTICS | VALUES<br>26MT | VALUES<br>36MT | UNITS            |  |
| 1                                 |                 | 25             | 35             | A                |  |
| IO                                | T <sub>C</sub>  | 70             | 60             | °C               |  |
| 1                                 | 50 Hz           | 360            | 475            | A                |  |
| IFSM                              | 60 Hz           | 375            | 500            |                  |  |
| l <sup>2</sup> t                  | 50 Hz           | 635            | 1130           | A <sup>2</sup> s |  |
| 60 Hz                             | 60 Hz           | 580            | 1030           | A-S              |  |
| V <sub>RRM</sub>                  |                 | 50 to 1600     |                | V                |  |
| TJ                                |                 | -55 to +150    |                | ٥C               |  |

## **ELECTRICAL SPECIFICATIONS**

| VOLTAGE RATINGS |                 |  |  |   |
|-----------------|-----------------|--|--|---|
| TYPE NUMBER     | VOLTAGE<br>CODE | V <sub>RRM</sub> , MAXIMUM REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE<br>PEAK REVERSE VOLTAGE<br>V | I <sub>RRM</sub> MAXIMUM<br>AT T <sub>J</sub> MAXIMUM<br>mA |
|                 | 05              | 50   | 75   |   |
|                 | 10              | 100  | 150  |   |
|                 | 20              | 200  | 275  |   |
|                 | 40              | 400  | 500  |   |
| VS-26MT         | 60              | 600  | 725  | 2   |
| VS-36MT         | 80              | 800  | 900  | 2   |
|                 | 100             | 1000   | 1100   |   |
|                 | 120             | 1200   | 1300   |   |
|                 | 140             | 1400   | 1500   |   |
|                 | 160             | 1600   | 1700   |   |

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| FORWARD CONDUCTION  |                     |  |                        |                       |                |                |                  |
|---|---------------------|--|------------------------|-----------------------|----------------|----------------|------------------|
| PARAMETER   | SYMBOL              |  | TEST CONDI             | TIONS                 | VALUES<br>26MT | VALUES<br>36MT | UNITS            |
| Maximum DC output current at T <sub>C</sub>               | lo                  | 120° rect. conduction angle  |                        | 25                    | 35             | А              |                  |
| Maximum DC output current at T <sub>C</sub>               | 10                  | 120 1601.001   | duction angle          |                       | 70             | 60             | °C               |
|   |                     | t = 10 ms  | No voltage             |                       | 360            | 475            | A                |
| Maximum peak, one-cycle<br>non-repetitive forward current | I <sub>FSM</sub>    | t = 8.3 ms   | reapplied              |                       | 375            | 500            |                  |
|   |                     | t = 10 ms  | 100 % V <sub>RRM</sub> |                       | 300            | 400            |                  |
|   |                     | t = 8.3 ms   | reapplied              | Initial               | 314            | 420            |                  |
| Maximum I <sup>2</sup> t for fusing                       | l <sup>2</sup> t    | t = 10 ms  | No voltage             | $T_J = T_J maximum$   | 635            | 1130           | A <sup>2</sup> s |
|   |                     | t = 8.3 ms   | reapplied              |                       | 580            | 1030           |                  |
|   |                     | t = 10 ms  | 100 % V <sub>RRM</sub> |                       | 450            | 50 800         |                  |
|   |                     | t = 8.3 ms   | reapplied              |                       | 410            | 730            |                  |
| Maximum I <sup>2</sup> √t for fusing                      | l²√t                | $l^2t$ for time $t_x$ = $l^2 \sqrt{t} \; x \; \sqrt{t_x}; \; 0.1 \leq t_x \leq 10 \; \text{ms}, \; V_{\text{RRM}}$ = 0 V |                        | 6360                  | 11 300         | A²√s           |                  |
| Low level of threshold voltage                            | V <sub>F(TO)1</sub> | (16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), T <sub>J</sub> maximum  |                        | 0.88                  | 0.86           | v              |                  |
| High level of threshold voltage                           | V <sub>F(TO)2</sub> | $(I > \pi x I_{F(AV)}), T_J$ maximum   |                        | 1.13                  | 1.03           | v              |                  |
| Low level forward slope resistance                        | r <sub>t1</sub>     | (16.7 % x $\pi$ x I <sub>F(AV)</sub> < I < $\pi$ x I <sub>F(AV)</sub> ), T <sub>J</sub> maximum                          |                        | 7.9                   | 6.3            | mΩ             |                  |
| High level forward slope resistance                       | r <sub>t2</sub>     | $(I > \pi x I_{F(AV)}), T_J$ maximum   |                        | 5.2                   | 5.0            | 1115.2         |                  |
| Maximum forward voltage drop                              | V <sub>FM</sub>     | $T_J = 25 \text{ °C}, I_{FM} = 40 \text{ A}_{pk}$ - per single junction  |                        | 1.26                  | 1.19           | V              |                  |
| Maximum DC reverse current                                | I <sub>RRM</sub>    | T <sub>J</sub> = 25 °C, per junction at rated V <sub>RRM</sub>   |                        | 1(                    | 00             | μΑ             |                  |
| RMS isolation voltage                                     | V <sub>INS</sub>    | T <sub>J</sub> = 25 °C, all  | terminal shorte        | d; f = 50 Hz, t = 1 s | 27             | 00             | V                |

| THERMAL - MECHANICAL SPECIFICATIONS            |                                   |  |                |                |       |  |
|--|-----------------------------------|--|----------------|----------------|-------|--|
| PARAMETER                                      | SYMBOL                            | TEST CONDITIONS  | VALUES<br>26MT | VALUES<br>36MT | UNITS |  |
| Maximum junction and storage temperature range | T <sub>J</sub> , T <sub>Stg</sub> |  | -55 to         | +150           | °C    |  |
| Maximum thermal resistance, junction to case   | R <sub>thJC</sub>                 | DC operation per bridge<br>(based on total power loss of bridge) | 1.42           | 1.35           | — К/W |  |
| Maximum thermal resistance, case to heatsink   | R <sub>thCS</sub>                 | Mounting surface, smooth, flat and greased                       | 0.2            | 0.2            |       |  |
| Approximate weight                             |                                   |  | 2              | 0              | g     |  |
| Mounting torque ± 10 %                         |                                   | Bridge to heatsink with screw M4                                 | 2              | .0             | Nm    |  |

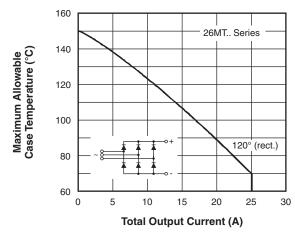


Fig. 1 - Current Ratings Characteristics

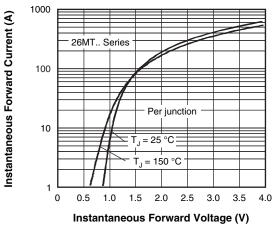


Fig. 2 - Forward Voltage Drop Characteristics

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2

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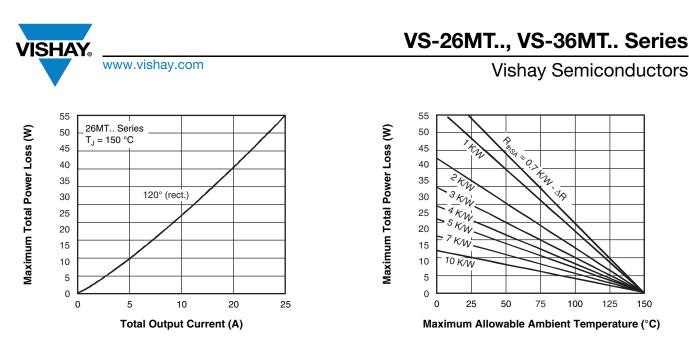


Fig. 3 - Total Power Loss Characteristics

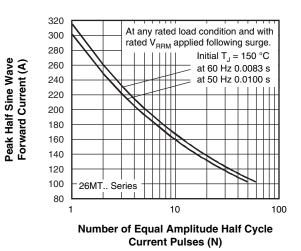


Fig. 4 - Maximum Non-Repetitive Surge Current

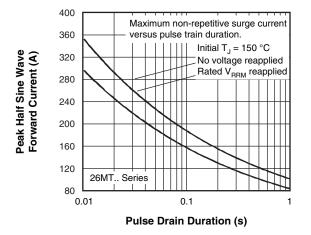


Fig. 5 - Maximum Non-Repetitive Surge Current

150 36MT.. Series 130 Maximum Allowable Case Temperature (°C) 110 90 120° (rect.) 70 50 0 5 10 15 20 25 30 35 40 **Total Output Current (A)** 

Fig. 6 - Current Ratings Characteristics

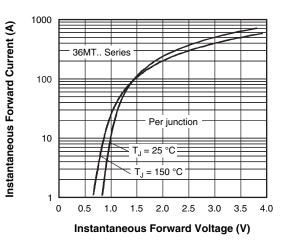


Fig. 7 - Forward Voltage Drop Characteristics

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3

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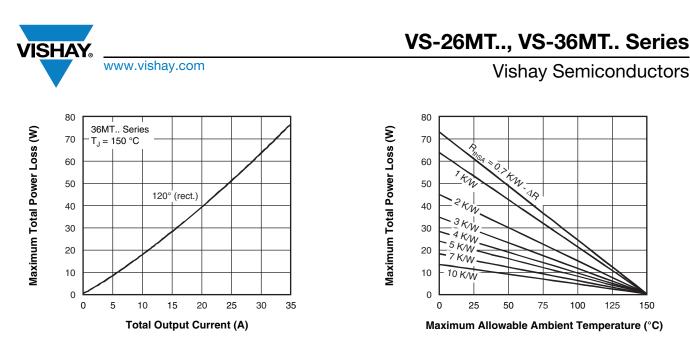


Fig. 8 - Total Power Loss Characteristics

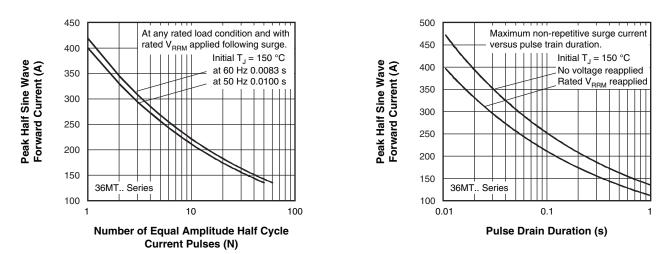
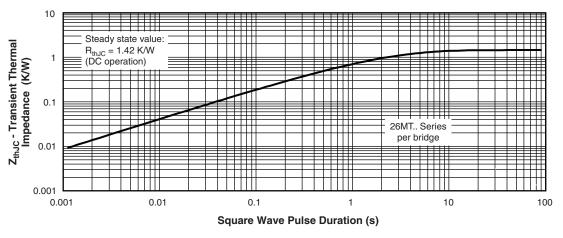


Fig. 9 - Maximum Non-Repetitive Surge Current

Fig. 10 - Maximum Non-Repetitive Surge Current







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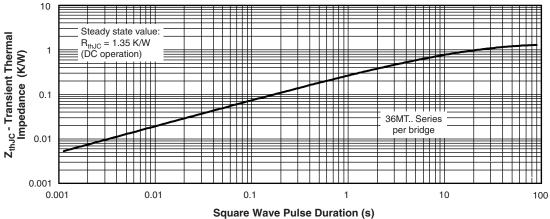
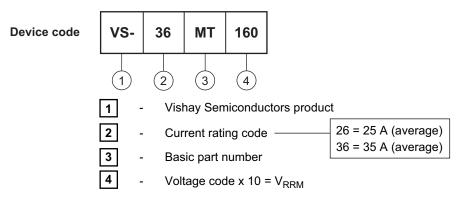
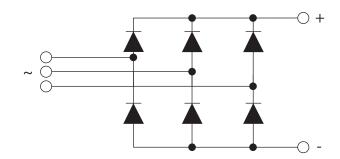


Fig. 12 - Thermal Impedance Z<sub>thJC</sub> Characteristics

## **ORDERING INFORMATION TABLE**



## **CIRCUIT CONFIGURATION**



| LINKS TO RELATED DOCUMENTS |                          |  |  |
|----------------------------|--------------------------|--|--|
| Dimensions                 | www.vishay.com/doc?95251 |  |  |



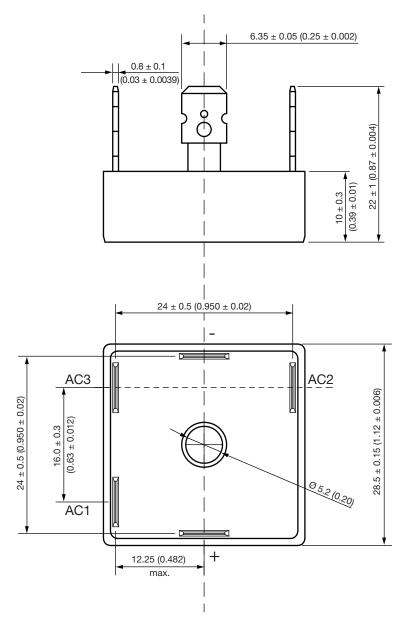


D-63

## **DIMENSIONS** in millimeters (inches)

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Not to scale



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